



50 MHz to 6000 MHz, CASCADABLE ACTIVE BIAS InGAP HBT MMIC AMPLIFIER



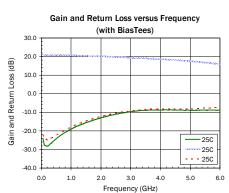
Package: SOT-89



Product Description

RFMD's SBB5089Z is a high performance InGaP HBT MMIC amplifier utilizing a Darlington configuration with an active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 5V supply, the SBB5089Z does not require a dropping resistor as compared to typical Darlington amplifiers. The SBB5089Z product is designed for high linearity 5V gain block applications that require small size and minimal external components. It is internally matched to $50\,\Omega$.





Features

- Wideband Flat Gain to 4GHz: ±1.1dB
- P_{1dB}=20.4dBm at 1950MHz
- Single Fixed 5V Supply
- Robust 1000V ESD, Class 1C
- Patented Thermal Design and Bias Circuit
- Low Thermal Resistance

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- Wideband Intrumentation
- Wireless Data, Satellite Terminals

Parameter	Specification			Unit	Condition
Parameter	Min.	Тур.	Max.	Unit	Condition
Small Signal Gain	19.0	20.5	22.0	dB	850MHz
	18.3	19.0	21.5	dB	1950MHz
	14.5	15.5	17.5	dB	6000MHz
Output Power at 1dB Compression		20.5		dBm	850 MHz
	19.0	20.0		dBm	1950MHz
Third Order Intercept Point		38.5		dBm	850 MHz
	33.0	35.0		dBm	1950MHz
Bandwidth		3000		MHz	Min. 10dB return loss (typ.)
Input Return Loss	10.0	13.0		dB	1950MHz
Output Return Loss	10.0	14.0		dB	1950MHz
Reverse Isolation		23.3		dB	1950MHz
Noise Figure		3.9	4.9	dB	1950MHz
Device Operating Voltage	4.75	5.0	5.25	V	
Device Operating Current	60.0	75.0	92.0	mA	
Thermal Resistance		69.9		°C/W	junction - lead

 $\textbf{Test Conditions: V}_{D} = 5\text{V}, \textbf{I}_{D} = 75 \text{ mA Typ.}, \textbf{OIP}_{3} \textbf{Tone Spacing} = \textbf{1MHz}, \textbf{P}_{OUT} \textbf{ per tone} = -d \textbf{Bm}, \textbf{T}_{L} = 25\,^{\circ}\text{C}, \textbf{Z}_{S} = \textbf{Z}_{L} = 50\,\Omega, \textbf{Tested with Bias Tees}$

SBB5089Z



Absolute Maximum Ratings

Parameter	Rating	Unit
Device Current (I _D)	100	mA
Max Device Voltage (V _D)	5.5	V
Max RF Input Power	24	dBm
Max Operating Dissipated Power	0.55	W
Junction Temp (T _J)	+150	°C
Operating Temp Range (T _L)	-40 to +105	°C
Storage Temp Range	-40 to +150	°C
ESD Rating - Human Body Model (HBM)	Class 1C	
Moisture Sensitivity Level	MSL2	

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression: $I_DV_D\!<\!(T_J\!-\!T_L)/\,R_{TH},j\!-\!l$ and $T_L\!=\!T_{LEAD}$



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent demage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

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Typical Performance at Key Operating Frequencies (0.5 GHz to 3.5 GHz Application Circuit)

Parameter	Specification		Unit	Condition	
raiametei	Min.	Тур.	Max.	Oilit	Condition
Small Signal Gain		21.1		dB	50MHz
		20.9		dB	100MHz
		20.8		dB	200 MHz
		20.8		dB	500 MHz
		20.8		dB	850MHz
		20.1		dB	1950MHz
		19.8		dB	2500MHz
		18.7		dB	3500MHz
		17.8		dB	4000MHz
Output Third Order Intercept Point		36		dBm	50MHz
		37.8		dBm	100MHz
		37.5		dBm	200 MHz
		38.6		dBm	500 MHz
		39.2		dBm	850 MHz
		34.9		dBm	1950MHz
		32.8		dBm	2500MHz
		29.4		dBm	3500MHz
		26.8		dBm	4000MHz
Output Power at 1dB Compression		19.4		dBm	50MHz
		19.7		dBm	100MHz
		20		dBm	200 MHz
		20.5		dBm	500 MHz
		20.4		dBm	850MHz
		20.4		dBm	1950MHz
		19.4		dBm	2500MHz
		16.9		dBm	3500MHz
		14.7		dBm	4000MHz





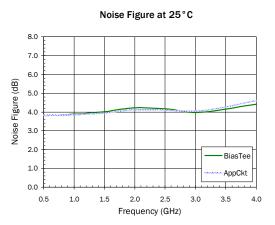
Parameter	Specification			Heit	Condition
	Min.	Тур.	Max.	Unit	Condition
Input Return Loss		11.3		dB	50MHz
		17.4		dB	100 MHz
		24.3		dB	200 MHz
		27.2		dB	500 MHz
		22.7		dB	850MHz
		14.6		dB	1950MHz
		12.9		dB	2500MHz
		10.6		dB	3500MHz
		11.6		dB	4000MHz
Output Return Loss		15.9		dB	50MHz
		21.7		dB	100 MHz
		30.4		dB	200 MHz
		31.8		dB	500MHz
		21.5		dB	850MHz
		13.5		dB	1950MHz
		12.0		dB	2500MHz
		13.5		dB	3500MHz
		27.5		dB	4000MHz
Reverse Isolation		17.4		dB	50MHz
		17.5		dB	100 MHz
		17.5		dB	200 MHz
		22.7		dB	500MHz
		22.8		dB	850MHz
		23.4		dB	1950MHz
		23.7		dB	2500MHz
		24.7		dB	3500MHz
		25.7		dB	4000MHz
Noise Figure		4.4		dB	50MHz
		4.4		dB	100 MHz
		4.3		dB	200 MHz
		3.8		dB	500 MHz
		3.8		dB	850MHz
		4.1		dB	1950MHz
		4.1		dB	2500MHz
		4.3		dB	3500 MHz
		4.6		dB	4000MHz

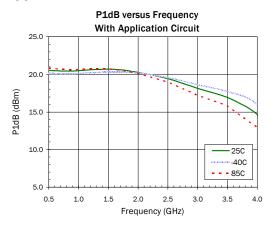
Test Conditions: V_{CC} =5V, I_D =75 mA Typ., OIP_3 Tone Spacing=1MHz, P_{OUT} per tone=0dBm, T_L =25 °C, Z_S = Z_L =50 Ω

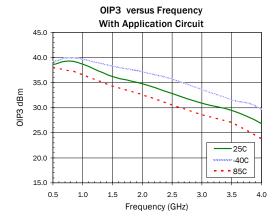
SBB5089Z



500MHz to 3.5GHz Application Circuit

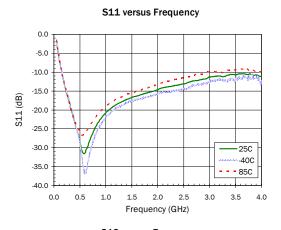


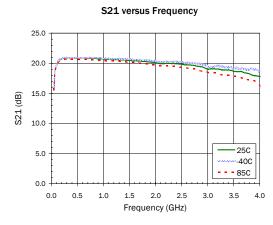


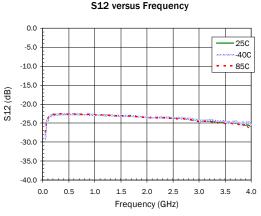


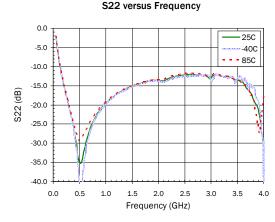


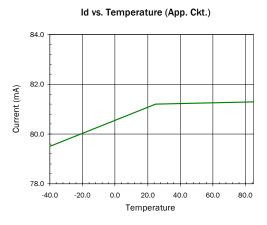
0.5 GHz to 3.5 GHz Application Circuit S-Parameters Over Temperature

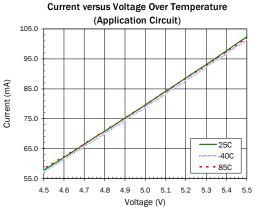








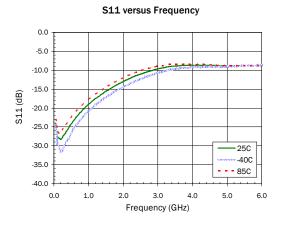


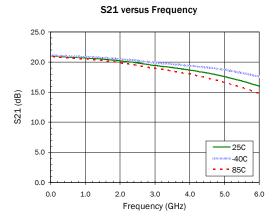


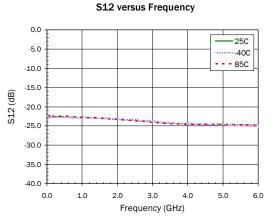
SBB5089Z

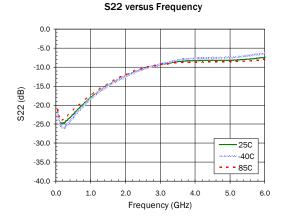


S-Parameters Over Temperature (Bias Tee)



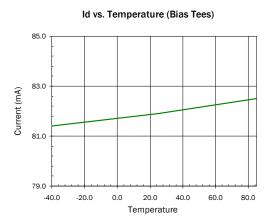


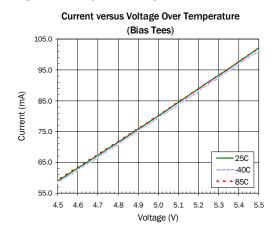






Device Current Over Temperature (Bias Tee)

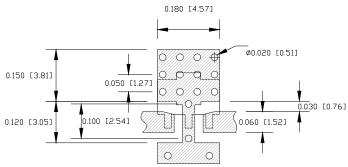






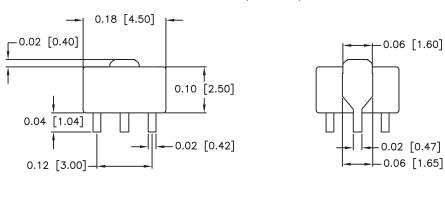
Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible
3	RF OUT/	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.
	BIAS	auon.

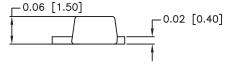
Suggested PCB Pad Layout



Nominal Package Dimensions

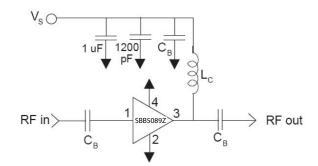
Dimensions in inches (millimeters)







Application Schematic

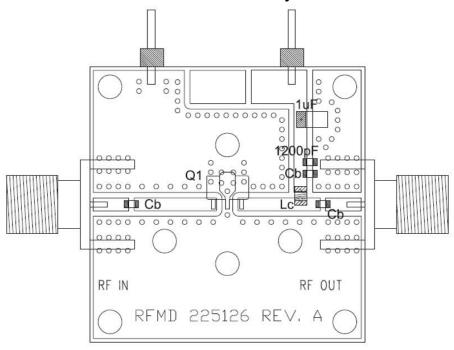


Reference Designator	Frequency (MHz) 500 to 3500
C _B	68 pF
L _C	82nH 0805CS

Note: For frequencies under 500 MHz, make the following changes: $C_{\text{B=}.1\text{uF}}$

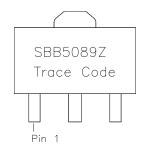
L_{C=330nH}

Evaluation Board Layout





Package Marking



Ordering Information

Ordering Code	Description
SBB5089Z	7" Reel with 1000 pieces
SBB5089ZSQ	Sample Bag with 25 pieces
SBB5089ZSR	7" Reel with 100 pieces
SBB5089ZPCK1	500MHz to 3500MHz PCBA with 5-piece sample bag